

※ 考生請注意：本試題  可  不可 使用計算機

1. Each diode cut-in voltage in the circuit in Figure 1 is 0.7V. Determine  $I_{D1}$ ,  $I_{D2}$ ,  $I_{D3}$ , and  $v_o$  for  $v_i = 3.0$  V. (12%)
2. Consider the circuit shown in Figure 2. The threshold voltages of the n-channel transistors are  $V_{TN} = 0.8$  V, and the threshold voltages of the p-channel transistors are  $V_{TP} = -0.8$  V. The conduction parameters are all equal. If  $v_{o2} = 0.6$  V, determine the values of  $v_{o3}$ ,  $v_{o1}$ , and  $v_i$ . (18%)
3. Consider the circuit shown in Figure 3 with transistor parameters of  $\beta_1 = \beta_2 = 120$ ,  $V_{BE1(on)} = V_{BE2(on)} = 0.7$  V, and  $V_{A1} = V_{A2} = \infty$ . (a) Determine the overall small-signal voltage gain  $A_v = v_o / v_s$ . (b) Determine the input resistance  $R_{is}$  and the output resistance  $R_o$ . (c) Determine the maximum undistorted swing in the output voltage. (20%)
4. Consider the amplifier whose small-signal AC equivalent circuit is shown in Figure 4, assume that the parameter values for the circuit are given as follows.  
 $C_c = 1 \mu\text{F}$ ,  $C_1 = 10 \text{ pF}$ ,  $C_2 = 1 \text{ pF}$ ,  $R_s = 75 \Omega$ ,  $R_{in} = 2.5 \text{ k}\Omega$ ,  $R_L = 1 \text{ k}\Omega$ ,  $g_m = 0.04 \text{ A/V}$ .  
 (a) Find the upper and lower 3-dB frequencies of the frequency response. (10%)  
 (b) What is the gain-bandwidth product for this amplifier? (5%)
5. An amplifier has a dc gain of  $10^5$  and poles at  $10^4$  Hz,  $10^6$  Hz, and  $10^8$  Hz. If this amplifier is operated in a closed negative feedback loop with a frequency-independent feedback factor  $\beta$ .  
 (a) Is this amplifier unity-gain stable? Please explain the reason for your answer. (7%)  
 (b) What are the gain and phase margins if the amplifier is operated with  $\beta = \frac{1}{100}$ ? (8%)
6. It is required to design a class B amplifier with the output voltage across a load  $R_L = 8 \Omega$  shown in the Figure 5. Neglecting the effects of finite  $V_{BE}$  and  $V_{CEsat}$ .  
 (a) Determine the load power, the supply power, and the power-conversion efficiency. (12%)  
 (b) Find the maximum power dissipation  $P_D$  in the transistors. (8%)

(背面仍有題目,請繼續作答)

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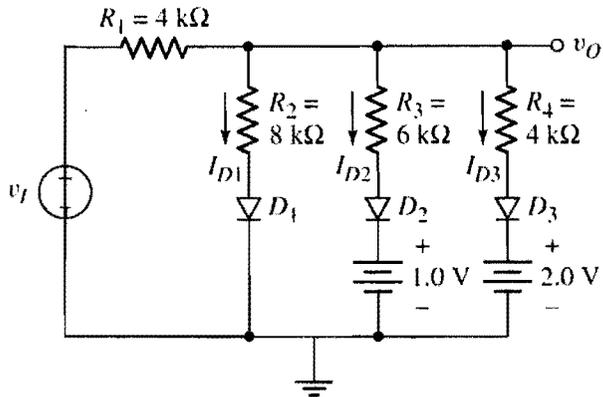


Figure 1

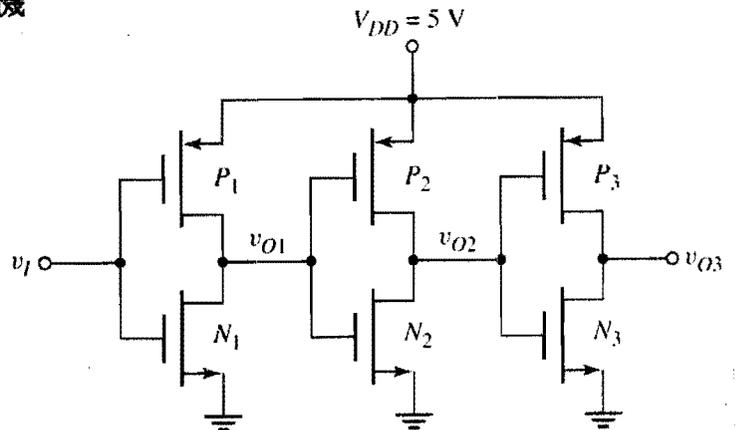


Figure 2

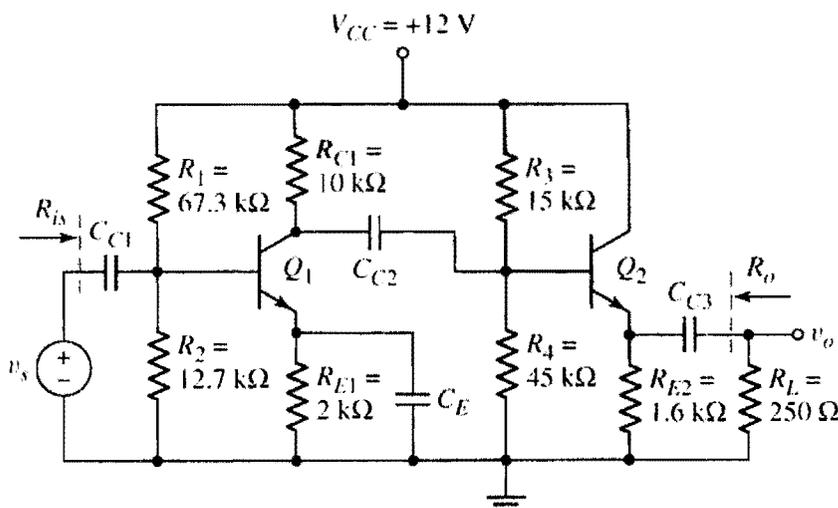


Figure 3

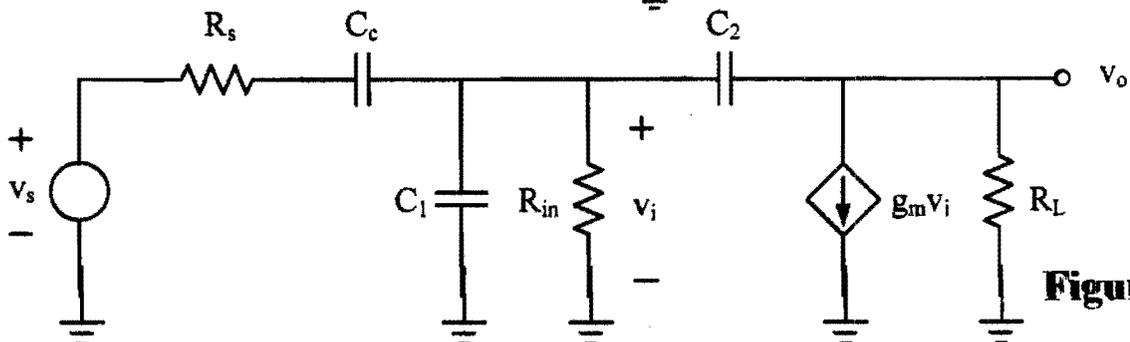
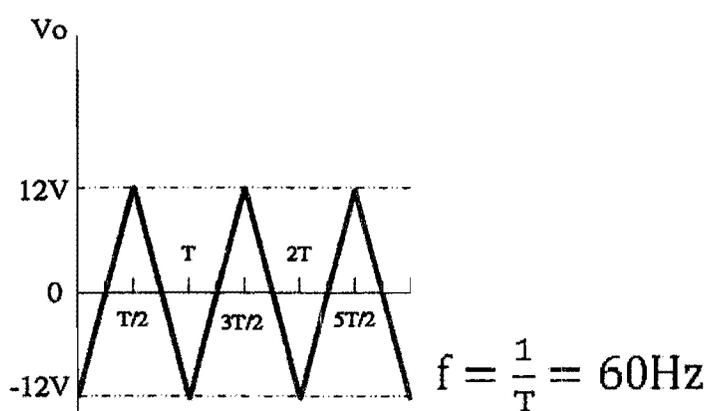
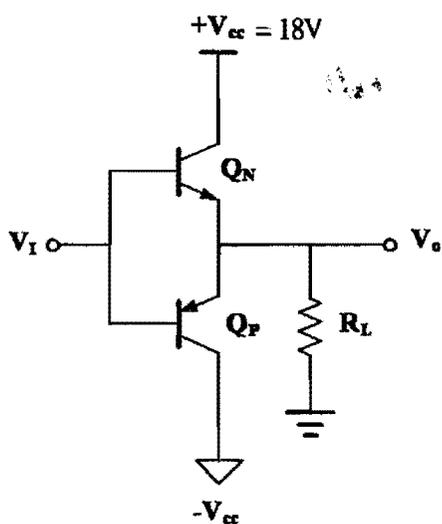


Figure 4



Output waveform

Figure 5